

isc N-Channel MOSFET Transistor

2SK1946

FEATURES

- Drain Current –I_D= 45A@ T_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage-: V_{DSS}=60V(Min)
- Static Drain-Source On-Resistance
- : $R_{DS(on)} = 0.022 \Omega$ (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

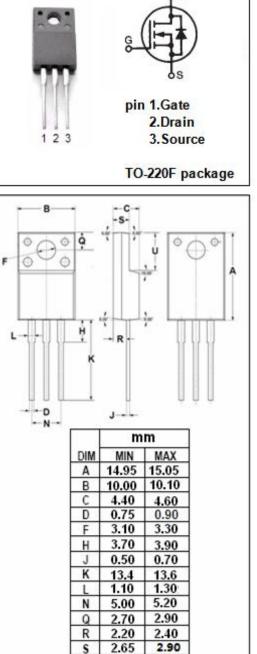
 motor drive, DC-DC converter, power switch and solenoid drive.

| ABSOLUTE MAXIMUM RATINGS(Ta=25 C) | | | | | | | |
|-----------------------------------|-------------------------------------|--------------------|------|--|--|--|--|
| SYMBOL | PARAMETER VALUE | | UNIT | | | | |
| V _{DSS} | Drain-Source Voltage | 60 | V | | | | |
| V _{GS} | Gate-Source Voltage-Continuous | ±20 | V | | | | |
| ID | Drain Current-Continuous | rent-Continuous 45 | | | | | |
| I _{DM} | Drain Current-Single Pluse | 180 | A | | | | |
| P _D | Total Dissipation @Tc=25℃ | 50 | W | | | | |
| TJ | Max. Operating Junction Temperature | 150 | °C | | | | |
| T _{stg} | Storage Temperature | -55~150 | °C | | | | |
| | | | | | | | |

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | МАХ | UNIT |
|---------------------|--------------------------------------|-----|------|
| R _{th j-c} | Thermal Resistance, Junction to Case | 2.5 | °C/W |



6.40

11

6.60

isc website: www.iscsemi.com

¹ *isc & iscsemi* is registered trademark



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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | МАХ | UNIT |
|----------------------|---------------------------------|---|-----|-------|------|
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} = 0; I _D = 1mA | 60 | | V |
| $V_{GS(th)}$ | Gate Threshold Voltage | V _{DS} = 10V; I _D = 1mA | 1.5 | 2.5 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D = 22.5A | | 0.022 | Ω |
| I _{GSS} | Gate-Body Leakage Current | V _{GS} = ±20V;V _{DS} = 0 | | 0.1 | uA |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} =60V; V _{GS} = 0 | | 500 | uA |
| Vsd | Forward On-Voltage | I _S = 45A; V _{GS} = 0 | | 2.25 | V |

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